

BGD704

750 MHz, 20 dB gain power doubler amplifier

Rev. 07 — 1 April 2005

Product data sheet

1. Product profile

1.1 General description

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC).

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability

1.3 Applications

- CATV systems in the frequency range of 40 MHz to 750 MHz

1.4 Quick reference data

Table 1: Quick reference data

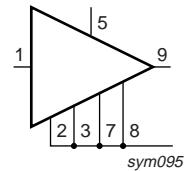
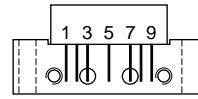
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$f = 50$ MHz	19.5	20	20.5	dB
		$f = 750$ MHz	20	21	-	dB
I_{tot}	total current consumption (DC)	$V_B = 24$ V	-	425	435	mA

PHILIPS

2. Pinning information

Table 2: Pinning

Pin	Description	Simplified outline	Symbol
1	input		
2	common		
3	common		
5	+V _B		
7	common		
8	common		
9	output		



sym095

3. Ordering information

Table 3: Ordering information

Type number	Package			Version
	Name	Description		
BGD704	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 × 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads		SOT115J

4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _i	RF input voltage		-	65	dBmV
T _{stg}	storage temperature		-40	+100	°C
T _{mb}	mounting base operating temperature		-20	+100	°C

5. Characteristics

Table 5: Characteristics

Bandwidth 40 MHz to 750 MHz; V_B = 24 V; T_{mb} = 35 °C; Z_S = Z_L = 75 Ω.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G _p	power gain	f = 50 MHz		19.5	20	20.5 dB
		f = 750 MHz	20	21	-	dB
SL	slope cable equivalent	f = 40 MHz to 750 MHz	0	1	2	dB
FL	flatness of frequency response	f = 40 MHz to 750 MHz	-	±0.2	±0.5	dB
S ₁₁	input return losses	f = 40 MHz to 80 MHz	20	31	-	dB
		f = 80 MHz to 160 MHz	19	29	-	dB
		f = 160 MHz to 320 MHz	18	25	-	dB
		f = 320 MHz to 640 MHz	17	21	-	dB
		f = 640 MHz to 750 MHz	16	21	-	dB

Table 5: Characteristics ...continued

Bandwidth 40 MHz to 750 MHz; $V_B = 24$ V; $T_{mb} = 35^\circ C$; $Z_S = Z_L = 75 \Omega$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
S_{22}	output return losses	$f = 40$ MHz to 80 MHz	20	26	-	dB	
		$f = 80$ MHz to 160 MHz	19	27	-	dB	
		$f = 160$ MHz to 320 MHz	18	26	-	dB	
		$f = 320$ MHz to 640 MHz	17	24	-	dB	
		$f = 640$ MHz to 750 MHz	16	23	-	dB	
S_{21}	phase response	$f = 50$ MHz	-45	-	+45	deg	
CTB	composite triple beat	110 channels flat; $V_o = 44$ dBmV; measured at 745.25 MHz	-	-58	-57	dB	
X_{mod}	cross modulation	110 channels flat; $V_o = 44$ dBmV; measured at 55.25 MHz	-	-63	-61	dB	
CSO	composite second order distortion	110 channels flat; $V_o = 44$ dBmV; measured at 746.5 MHz	-	-61	-56	dB	
d_2	second order distortion		[1]	-	-75	-66	dB
V_o	output voltage	$d_{im} = -60$ dB	[2]	60.5	63.5	-	dBmV
F	noise figure	$f = 50$ MHz	-	4.5	5	dB	
		$f = 450$ MHz	-	-	6.5	dB	
		$f = 550$ MHz	-	-	7	dB	
		$f = 600$ MHz	-	-	7	dB	
		$f = 750$ MHz	-	6.5	8.5	dB	
I_{tot}	total current consumption (DC)		[3]	-	425	435	mA

[1] $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 691.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 746.5$ MHz.[2] Measure according to DIN45004B; $f_p = 740.25$ MHz; $V_p = V_o$; $f_q = 747.25$ MHz; $V_q = V_o - 6$ dB; $f_r = 749.25$ MHz; $V_r = V_o - 6$ dB; measured at $f_p + f_q - f_r = 738.25$ MHz.[3] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

Table 6: Characteristics

Bandwidth 40 MHz to 600 MHz; $V_B = 24$ V; $T_{mb} = 35^\circ C$; $Z_S = Z_L = 75 \Omega$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$f = 50$ MHz	19.5	20	20.5	dB
		$f = 600$ MHz	20	20.7	-	dB
SL	slope cable equivalent	$f = 40$ MHz to 600 MHz	0	-	2	dB
FL	flatness of frequency response	$f = 40$ MHz to 600 MHz	-	-	± 0.3	dB
S_{11}	input return losses	$f = 40$ MHz to 80 MHz	20	31	-	dB
		$f = 80$ MHz to 160 MHz	19	29	-	dB
		$f = 160$ MHz to 320 MHz	18	25	-	dB
		$f = 320$ MHz to 600 MHz	17	21	-	dB
S_{22}	output return losses	$f = 40$ MHz to 80 MHz	20	26	-	dB
		$f = 80$ MHz to 160 MHz	19	27	-	dB
		$f = 160$ MHz to 320 MHz	18	26	-	dB
		$f = 320$ MHz to 600 MHz	17	24	-	dB
S_{21}	phase response	$f = 50$ MHz	-45	-	+45	deg

Table 6: Characteristics ...continuedBandwidth 40 MHz to 600 MHz; $V_B = 24$ V; $T_{mb} = 35^\circ\text{C}$; $Z_S = Z_L = 75 \Omega$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
CTB	composite triple beat	85 channels flat; $V_o = 44$ dBmV; measured at 595.25 MHz	-	-65	-64	dB
X_{mod}	cross modulation	85 channels flat; $V_o = 44$ dBmV; measured at 55.25 MHz	-	-65	-64	dB
CSO	composite second order distortion	85 channels flat; $V_o = 44$ dBmV; measured at 596.5 MHz	-	-66	-58	dB
d_2	second order distortion		[1]	-	-	-68 dB
V_o	output voltage	$d_{\text{im}} = -60$ dB	[2]	63	-	- dBmV
F	noise figure	see Table 5	-	-	-	dBmV
I_{tot}	total current consumption (DC)		[3]	-	425	435 mA

[1] $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 541.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 596.5$ MHz.[2] Measured according to DIN45004B; $f_p = 590.25$ MHz; $V_p = V_o$; $f_q = 597.25$ MHz; $V_q = V_o - 6$ dB; $f_r = 599.25$ MHz; $V_r = V_o - 6$ dB; measured at $f_p + f_q - f_r = 588.25$ MHz.[3] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.**Table 7: Characteristics**Bandwidth 40 MHz to 550 MHz; $V_B = 24$ V; $T_{mb} = 35^\circ\text{C}$; $Z_S = Z_L = 75 \Omega$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$f = 50$ MHz	19.5	20	20.5	dB
		$f = 550$ MHz	20	20.6	-	dB
SL	slope cable equivalent	$f = 40$ MHz to 550 MHz	0	-	2	dB
FL	flatness of frequency response	$f = 40$ MHz to 550 MHz	-	-	± 0.3	dB
S_{11}	input return losses	$f = 40$ MHz to 80 MHz	20	31	-	dB
		$f = 80$ MHz to 160 MHz	19	29	-	dB
		$f = 160$ MHz to 320 MHz	18	25	-	dB
		$f = 320$ MHz to 550 MHz	17	21	-	dB
S_{22}	output return losses	$f = 40$ MHz to 80 MHz	20	26	-	dB
		$f = 80$ MHz to 160 MHz	19	27	-	dB
		$f = 160$ MHz to 320 MHz	18	26	-	dB
		$f = 320$ MHz to 550 MHz	17	24	-	dB
S_{21}	phase response	$f = 50$ MHz	-45	-	+45	deg
CTB	composite triple beat	77 channels flat; $V_o = 44$ dBmV; measured at 547.25 MHz	-	-67	-66	dB
X_{mod}	cross modulation	77 channels flat; $V_o = 44$ dBmV; measured at 55.25 MHz	-	-67	-66	dB
CSO	composite second order distortion	77 channels flat; $V_o = 44$ dBmV; measured at 548.5 MHz	-	-67	-60	dB
d_2	second order distortion		[1]	-	-	-70 dB
V_o	output voltage	$d_{\text{im}} = -60$ dB	[2]	63.5	-	- dBmV
F	noise figure	see Table 5	-	-	-	dB
I_{tot}	total current consumption (DC)		[3]	-	425	435 mA

[1] $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.

[2] Measure according to DIN45004B; $f_p = 540.25$ MHz; $V_p = V_o$; $f_q = 547.25$ MHz; $V_q = V_o - 6$ dB; $f_r = 549.25$ MHz; $V_r = V_o - 6$ dB; measured at $f_p + f_q - f_r = 538.25$ MHz.

[3] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

Table 8: Characteristics

Bandwidth 40 MHz to 450 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75$ Ω.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
G_p	power gain	$f = 50$ MHz	19.5	20	20.5	dB	
		$f = 450$ MHz	20	20.6	-	dB	
SL	slope cable equivalent	$f = 40$ MHz to 450 MHz	0	-	2	dB	
FL	flatness of frequency response	$f = 40$ MHz to 450 MHz	-	-	± 0.3	dB	
s_{11}	input return losses	$f = 40$ MHz to 80 MHz	20	31	-	dB	
		$f = 80$ MHz to 160 MHz	19	29	-	dB	
		$f = 160$ MHz to 320 MHz	18	25	-	dB	
		$f = 320$ MHz to 450 MHz	17	21	-	dB	
s_{22}	output return losses	$f = 40$ MHz to 80 MHz	20	26	-	dB	
		$f = 80$ MHz to 160 MHz	19	27	-	dB	
		$f = 160$ MHz to 320 MHz	18	26	-	dB	
		$f = 320$ MHz to 450 MHz	17	24	-	dB	
s_{21}	phase response	$f = 50$ MHz	-45	-	+45	deg	
CTB	composite triple beat	60 channels flat; $V_o = 46$ dBmV; measured at 445.25 MHz	-	-	-67	dB	
X_{mod}	cross modulation	60 channels flat; $V_o = 46$ dBmV; measured at 55.25 MHz	-	-	-64	dB	
CSO	composite second order distortion	60 channels flat; $V_o = 46$ dBmV; measured at 446.5 MHz	-	-	-63	dB	
d_2	second order distortion		[1]	-	-	-73	dB
V_o	output voltage	$d_{\text{im}} = -60$ dB	[2]	66	-	-	dBmV
F	noise figure	see Table 5	-	-	-	dB	
I_{tot}	total current consumption (DC)		[3]	-	425	435	mA

[1] $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.

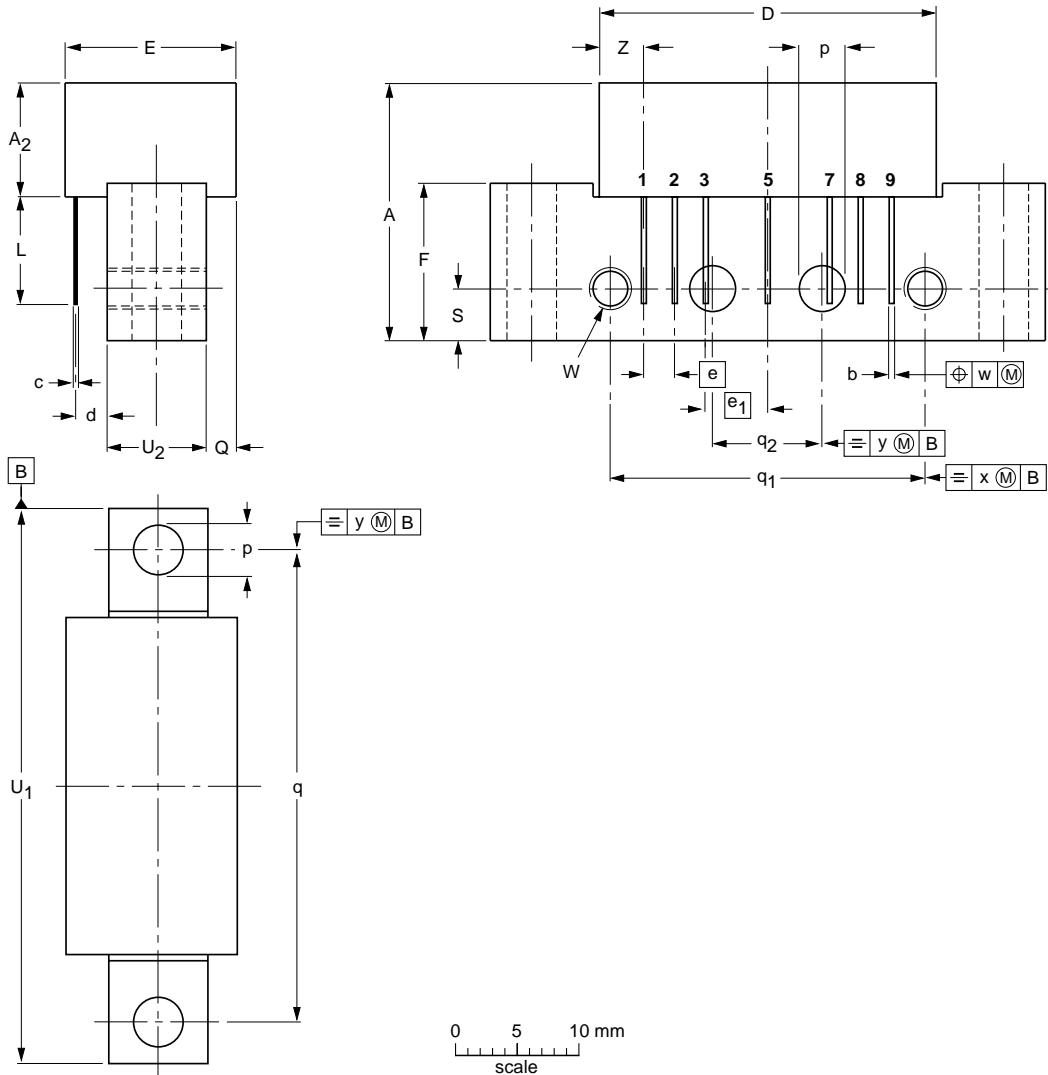
[2] Measured according to DIN45004B; $f_p = 440.25$ MHz; $V_p = V_o$; $f_q = 447.25$ MHz; $V_q = V_o - 6$ dB; $f_r = 449.25$ MHz; $V_r = V_o - 6$ dB; measured at $f_p + f_q - f_r = 438.25$ MHz.

[3] The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.

6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₂ max.	b	c	D max.	d max.	E max.	e	e ₁	F	L min.	p	Q max.	q	q ₁	q ₂	S	U ₁	U ₂	W	w	x	y	Z max.
mm	20.8	9.1	0.51 0.38	0.25	27.2	2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75 44.25	8.2 7.8	6-32 UNC	0.25	0.7	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT115J						-99-02-06- 04-02-04

Fig 1. Package outline SOT115J



7. Revision history

Table 9: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGD704_7	20050401	Product data sheet	-	9397 750 14776	BGD704_6
Modifications:	<ul style="list-style-type: none">The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors				
BGD704_6	20011102	Product specification	-	9397 750 09027	BGD704_5
BGD704_5	20011029	Product specification	-	9397 750 08846	BGD704_4
BGD704_4	19990322	Product specification	-	9397 750 05295	BGD704_3
BGD704_3	19970402	Product specification	-	9397 750 01971	BGD704_2
BGD704_2	19961220	Product specification	-	9397 750 01392	-

8. Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2][3]}	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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